

2SK2572(Tentative)

Silicon N-Channel Power F-MOS

■ Features

- Avalanche energy capability guaranteed
- High-speed switching
- Low ON-resistance
- No secondary breakdown

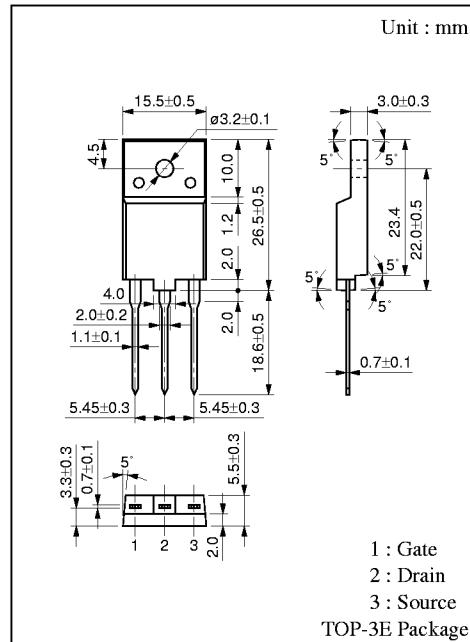
■ Applications

- Non-contact relay
- Solenoid drive
- Motor drive
- Control equipment
- Switching mode regulator

■ Absolute Maximum Ratings ($T_c = 25^\circ\text{C}$)

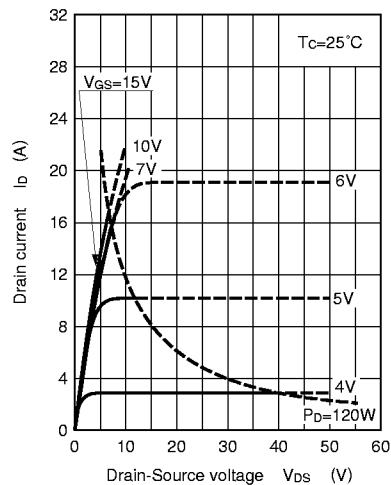
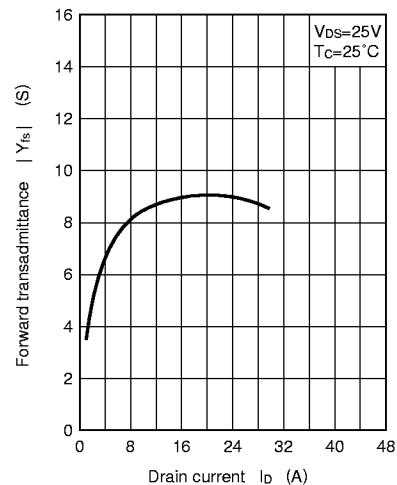
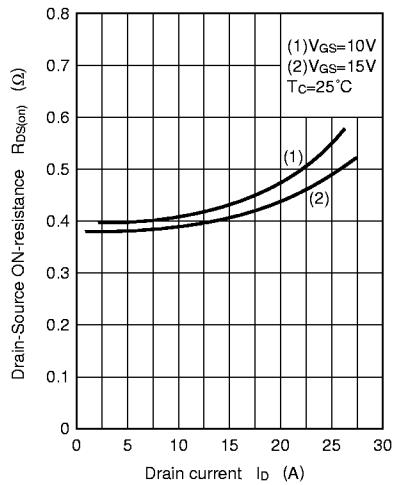
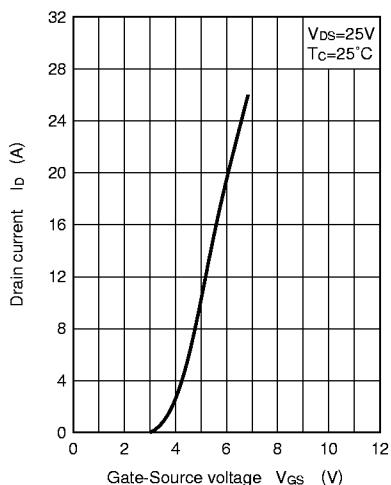
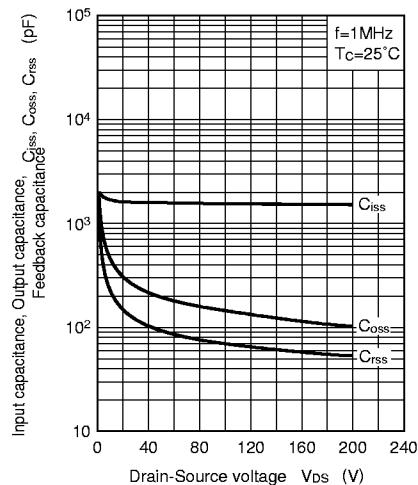
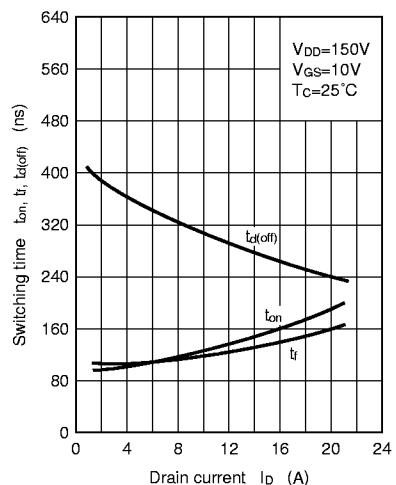
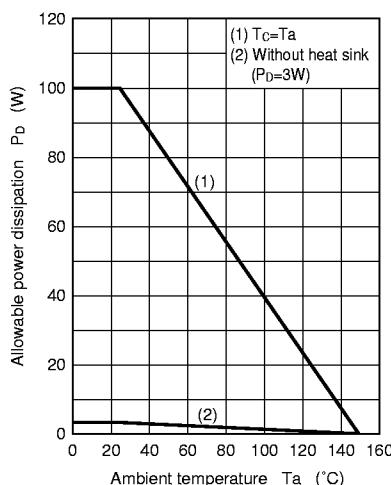
Parameter	Symbol	Rating	Unit
Drain-Source breakdown voltage	V_{DSS}	500	V
Gate-Source voltage	V_{GSS}	± 20	V
Drain current	DC I_D	± 15	A
	Pulse I_{DP}	± 30	A
Avalanche energy capability	EAS *	11.25	mJ
Allowable power dissipation	P_D	100	W
		3	
Channel temperature	T_{ch}	150	$^\circ\text{C}$
Storage temperature	T_{stg}	-55 to +150	$^\circ\text{C}$

* $L = 0.1\text{mH}$, $I_L = 15\text{A}$, 1 pulse

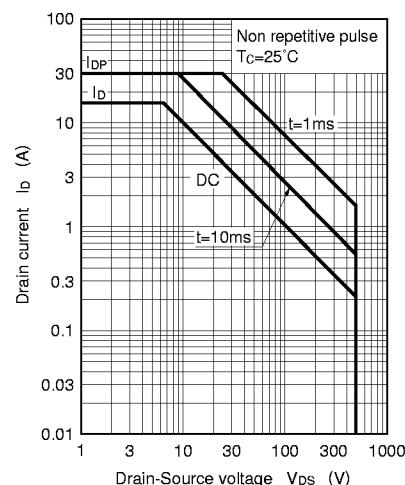


■ Electrical Characteristics ($T_c = 25^\circ\text{C}$)

Parameter	Symbol	Condition	Min	Typ	Max	Unit
Drain-Source cut-off current	I_{DSS}	$V_{DS} = 400\text{V}$, $V_{GS} = 0$			100	μA
Gate-Source leakage current	I_{GSS}	$V_{GS} = \pm 30\text{V}$, $V_{DS} = 0$			± 1	μA
Drain-Source breakdown voltage	V_{DSS}	$I_D = 1\text{mA}$, $V_{GS} = 0$	500			V
Gate threshold voltage	V_{th}	$V_{DS} = 25\text{V}$, $I_D = 1\text{mA}$	1		5	V
Drain-Source ON-resistance	$R_{DS(on)}$	$V_{GS} = 10\text{V}$, $I_D = 8\text{A}$		0.38	0.5	Ω
Forward transadmittance	$ Y_{fs} $	$V_{DS} = 25\text{V}$, $I_D = 8\text{A}$	5	8		S
Diode forward voltage	V_{DSF}	$I_{DR} = 15\text{A}$, $V_{GS} = 0$			-1.8	V
Input capacitance	C_{iss}	$V_{DS} = 20\text{V}$, $V_{GS} = 0$, $f = 1\text{MHz}$		1500		pF
Output capacitance	C_{oss}			300		pF
Feedback capacitance	C_{rss}			145		pF
Turn-on time	t_{on}	$V_{DD} = 150\text{V}$, $I_D = 8\text{A}$ $V_{GS} = 10\text{V}$, $R_L = 19\Omega$		110		ns
Fall time	t_f			100		ns
Turn-off time (delay time)	$t_{d(off)}$			330		ns
Channel-Case heat resistance	$R_{th(ch-c)}$				1.25	$^\circ\text{C}/\text{W}$
Channel-Atmosphere heat resistance	$R_{th(ch-a)}$				41.67	$^\circ\text{C}/\text{W}$

$I_D - V_{DS}$  $|Y_{fs}| - I_D$  $R_{DS(on)} - I_D$  $I_D - V_{GS}$  $C_{iss}, C_{oss}, C_{rss} - V_{DS}$  $t_{on}, t_f, t_{d(off)} - I_D$  $P_D - T_a$ 

Area of safe operation (ASO)

 $R_{DS(on)} - I_D$ 